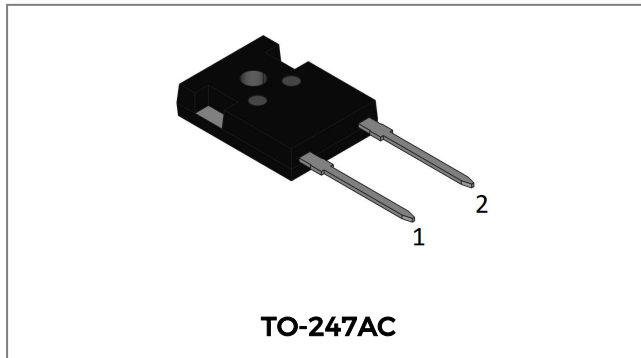


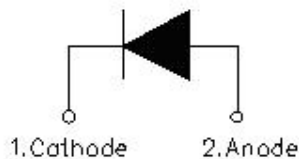
SDUR60FC120W ULTRAFAST RECTIFIER



Applications

- Anti parallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Circuit Diagram



Features

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Terminals finish: 100% Pure Tin
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	1200	V
Average Rectified Forward Current	$I_F(AV)$	$T_c=91^{\circ}C$, In DC	60	A
Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	8.3ms, Half Sine pulse, $T_c=25^{\circ}C$	500	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	V_{F1}	@60A, Pulse, $T_J = 25^\circ\text{C}$	3.0	3.5	V
	V_{F2}	@60A, Pulse, $T_J = 150^\circ\text{C}$	2.0	2.5	V
Reverse Current*	I_{R1}	@ $V_R = \text{rated } V_R$, $T_J = 25^\circ\text{C}$	0.1	10	μA
	I_{R2}	@ $V_R = \text{rated } V_R$, $T_J = 150^\circ\text{C}$	180	500	μA
Reverse Recovery Time	t_{rr1}	$I_F = 500\text{mA}$, $I_R = 1\text{A}$, and $I_{rm} = 250\text{mA}$, $T_J = 25^\circ\text{C}$	52	65	ns
Reverse Recovery Time	t_{rr}	$I_F = 1\text{A}$, $di_F/dt = -50\text{A}/\mu\text{s}$, $V_R = 30\text{V}$, $T_J = 25^\circ\text{C}$	50	-	ns
Reverse Recovery Time	t_{rr}	$I_F = 30\text{A}$, $di_F/dt = -200\text{A}/\mu\text{s}$, $V_R = 600\text{V}$, $T_J = 25^\circ\text{C}$	163	-	ns
Reverse Recovery Charge	Q_{rr}		557	-	nC
Reverse Recovery Current	I_{RRM}		6.2	-	A
Reverse Recovery Time	t_{rr}	$I_F = 30\text{A}$, $di_F/dt = -200\text{A}/\mu\text{s}$, $V_R = 600\text{V}$, $T_J = 125^\circ\text{C}$	250	-	ns
Reverse Recovery Charge	Q_{rr}		2407	-	nC
Reverse Recovery Current	I_{RRM}		13.7	-	A

* Pulse width < 300 μs , duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +175	$^\circ\text{C}$
Storage Temperature	T_{stg}	-	-55 to +175	$^\circ\text{C}$
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	0.4	$^\circ\text{C}/\text{W}$
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AC			

Ratings and Characteristics Curves

Figure 1 Typical Forward Characteristics

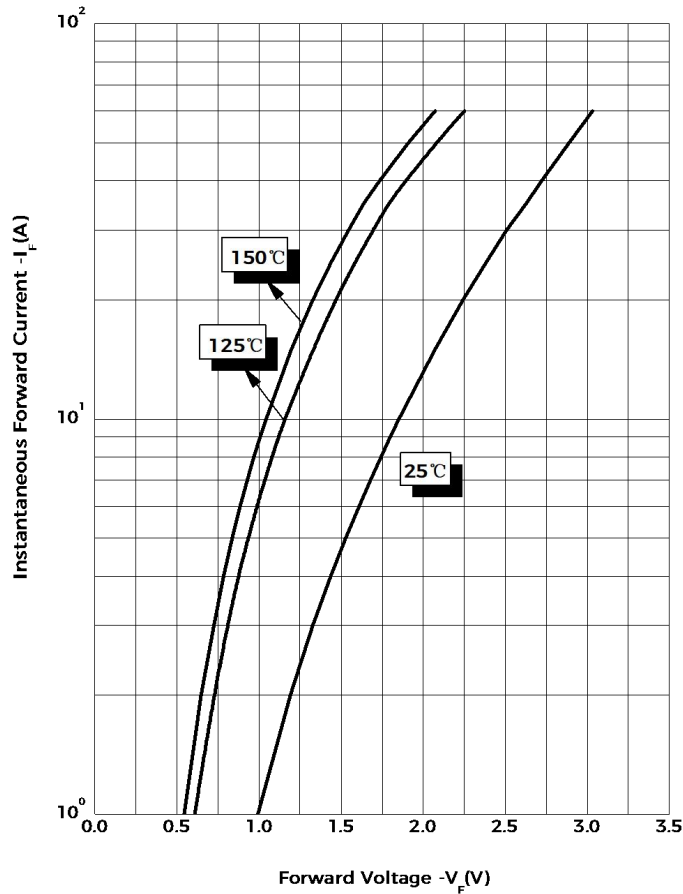


Figure 2 Typical Reverse Characteristics

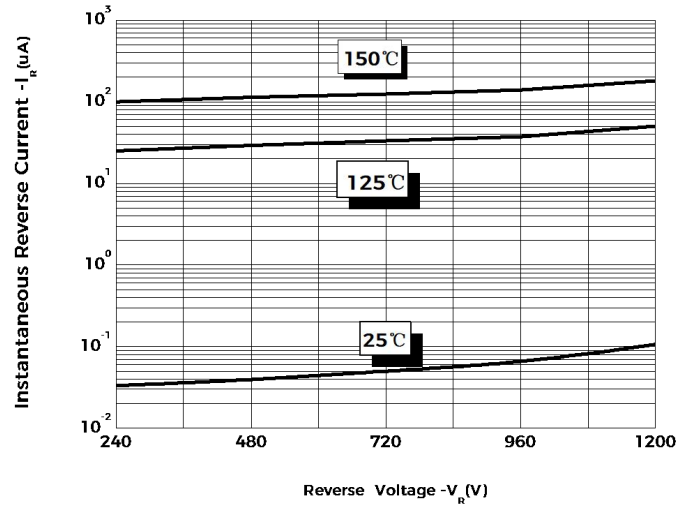
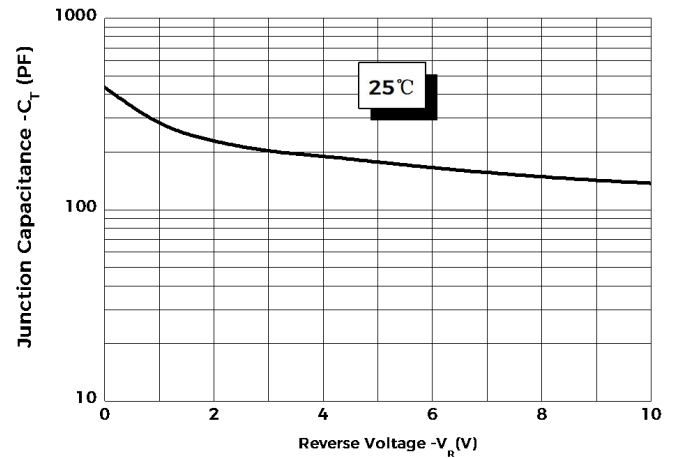
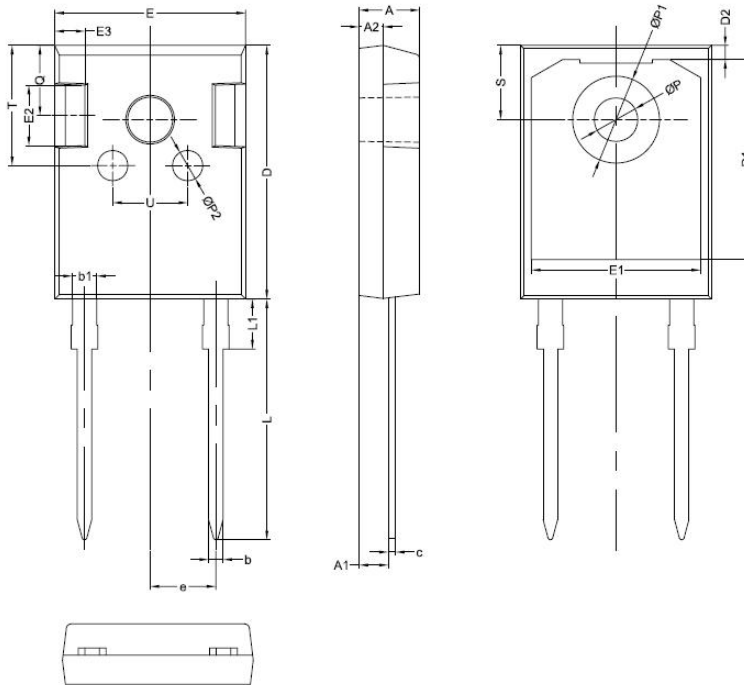


Figure 3 Typical Junction Capacitance

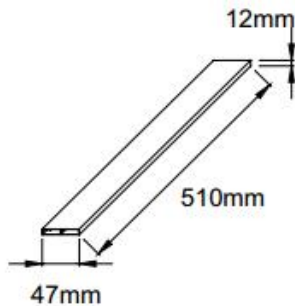


Mechanical Dimensions TO-247AC

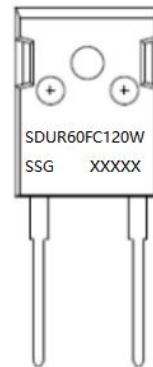


SYMBOL	Millimeters		
	MIN.	TYP.	MAX.
A	4.80	5.00	5.20
A1	2.20	2.41	2.61
A2	1.90	2.00	2.10
b	1.10	1.20	1.35
b1	1.80	2.00	2.20
c	0.50	0.60	0.75
D	20.30	21.00	21.20
D1		16.58	
D2		1.17	
E	15.60	15.80	16.00
E1		14.02	
E2		5.00	
E3		2.50	
e		5.44	
L	19.42	19.92	20.42
L1		4.13	
P	3.50	3.60	3.70
P1	7.1	7.19	7.40
P2		2.50	
Q		5.80	
S	6.05	6.15	6.25
T		10.00	
U		6.20	

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

SDUR = Device Type
60 = Forward Current (60A)
FC = FC
120 = Reverse Voltage (1200V)
W = Configuration
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions : Molding resin
Epoxy resin UL : 94V-0

Ordering Information

Device	Package	Shipping
SDUR60FC120W	TO-247AC(Pb-Free)	25pcs / tube

Technical Data
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